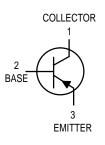
Amplifier Transistors

PNP Silicon





BC307

BC307B

CASE 29–04, STYLE 17 TO-92 (TO-226AA)

MOTOROLA

MAXIMUM RATINGS

Rating	Symbol	BC307, B, C	BC308C	Unit
Collector-Emitter Voltage	VCEO	-45	-25	Vdc
Collector-Base Voltage	V _{CBO}	-50	-30	Vdc
Emitter-Base Voltage	VEBO	-5.0		Vdc
Collector Current — Continuous	IС	-100		mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	350 2.8		mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.0 8.0		Watts mW/°C
Operating and Storage Junction Temperature Range	TJ, Tstg	-55 to +150		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	125	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage ($I_C = -2.0 \text{ mAdc}, I_B = 0$)	BC307,B,C BC308C	V _(BR) CEO	45 25	_	_	Vdc
Emitter-Base Breakdown Voltage (I _E = -100 μAdc, I _C = 0)	BC307,B,C BC308C	V _{(BR)EBO}	-5.0 -5.0	_	_	Vdc
Collector-Emitter Leakage Current ($V_{CES} = -50 V$, $V_{BE} = 0$) ($V_{CES} = -30 V$, $V_{BE} = 0$) ($V_{CES} = -50 V$, $V_{BE} = 0$) TA = 125°C ($V_{CES} = -30 V$, $V_{BE} = 0$) TA = 125°C	BC307,B,C BC308C BC307,B,C BC308C	ICES	 	-0.2 -0.2 -0.2 -0.2	-15 -15 -4.0 -4.0	nAdc μA

REV 1

BC307 BC307B BC307C BC308C

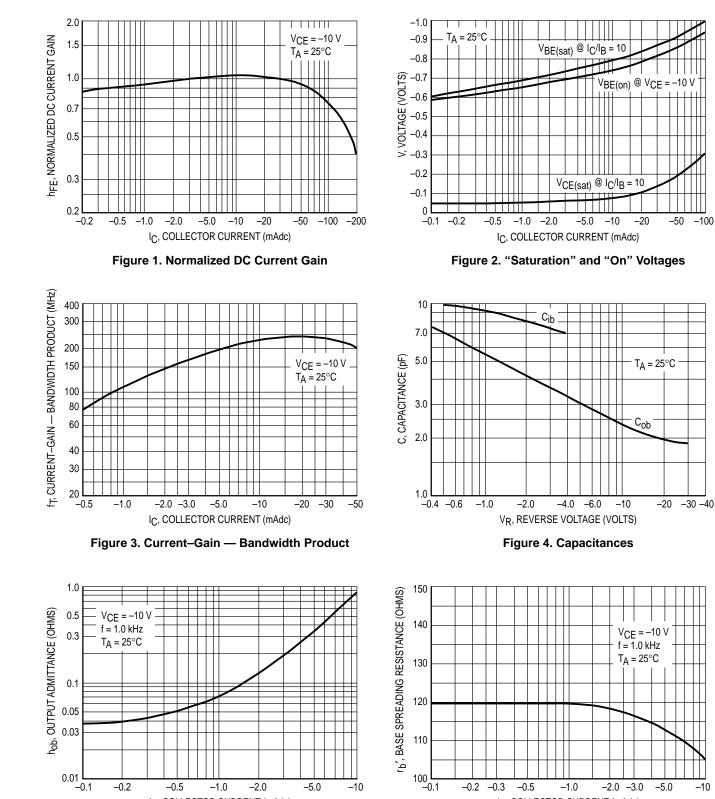
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS		•				
DC Current Gain (I _C = -10 μ Adc, V _{CE} = -5.0 Vdc)	BC307B BC307C/308C	hFE	_	150 270		_
$(I_{C} = -2.0 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	BC307 BC307B/308B BC307C/308C		120 200 420	 290 500	800 460 800	
$(I_{C} = -100 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	BC307B BC307C/308C		_	180 300	_	
Collector-Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}, I_B = -0.5 \text{ mAdc}$) ($I_C = -10 \text{ mAdc}, I_B = \text{see Note 1}$) ($I_C = -100 \text{ mAdc}, I_B = -5.0 \text{ mAdc}$)		V _{CE(sat)}	 	-0.10 -0.30 -0.25	-0.3 -0.6 	Vdc
Base-Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}, I_B = -0.5 \text{ mAdc}$) ($I_C = -100 \text{ mAdc}, I_B = -5.0 \text{ mAdc}$)		VBE(sat)		-0.7 -1.0		Vdc
Base–Emitter On Voltage (I _C = -2.0 mAdc, V _{CE} = -5.0 Vdc)		V _{BE(on)}	-0.55	-0.62	-0.7	Vdc
DYNAMIC CHARACTERISTICS						
Current-Gain — Bandwidth Product ($I_C = -10$ mAdc, $V_{CE} = -5.0$ Vdc, f = 100 MHz)	BC307,B,C BC308C	fT	_	280 320		MHz
Common Base Capacitance $(V_{CB} = -10 \text{ Vdc}, I_{C} = 0, f = 1.0 \text{ MHz})$		C _{cbo}	_	—	6.0	pF
Noise Figure (I _C = -0.2 mAdc, V _{CE} = -5.0 Vdc, R _S = 2.0 k Ω , f = 1.0 kHz)	BC307,B,C	NF	_	2.0	10	dB
$(I_{C} = -0.2 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc}, R_{S} = 2.0 \text{ k}\Omega, f = 1.0 \text{ kHz}, f = 200 \text{ Hz})$	BC308C		_	2.0	10	

1. I_C = -10 mAdc on the constant base current characteristic, which yields the point I_C = -11 mAdc, V_{CE} = -1.0 V.

BC307 BC307B BC307C BC308C

-100



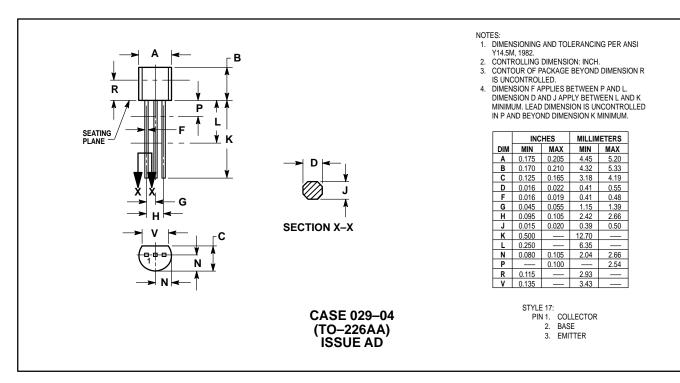
TYPICAL CHARACTERISTICS

IC, COLLECTOR CURRENT (mAdc) Figure 5. Output Admittance

IC, COLLECTOR CURRENT (mAdc) Figure 6. Base Spreading Resistance -10

BC307 BC307B BC307C BC308C

PACKAGE DIMENSIONS



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How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 303–675–2140 or 1–800–441–2447 JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 4–32–1, Nishi–Gotanda, Shinaqawa–ku, Tokyo 141, Japan. 81–3–5487–8488

Mfax™: RMFAX0@email.sps.mot.com - TOUCHTONE 602-244-6609 - US & Canada ONLY 1-800-774-18

INTERNET: http://motorola.com/sps



 - TOUCHTONE 602-244-6609
 ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,

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 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

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